NSN 5962-01-351-4975

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View Online at https://aerobasegroup.com/nsn/5962-01-351-4975

Overall Length:
1.060 inches
Overall Height:
0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.1 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Ticonderoga class cg (47); forrestal class cv; sturgeon class ssn (637); tactical satellite commuications system an/usc-38; tarawa class
lha; arleigh burke class ddg; nimitz class cvn; los angeles class ssn (688); wasp class lhd; spruancde class dd (963)
Features Provided:
Bidirectional and bipolar and w/clock
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
90.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
And-or invert gate array
Voltage Rating And Type Per Characteristic:

50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level

Time Rating Per Chacteristic:

output

-0.5 volts power source and 12.00 volts power source

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